# Micropower Undervoltage Sensing Circuits

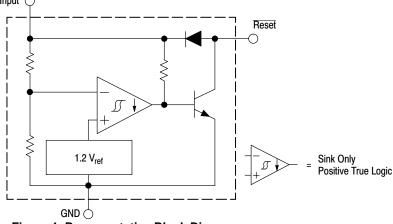
The MC34164 series are undervoltage sensing circuits specifically designed for use as reset controllers in portable microprocessor based systems where extended battery life is required. These devices offer the designer an economical solution for low voltage detection with a single external resistor. The MC34164 series features a bandgap reference, a comparator with precise thresholds and built–in hysteresis to prevent erratic reset operation, an open collector reset output capable of sinking in excess of 6.0 mA, and guaranteed operation down to 1.0 V input with extremely low standby current. The MC devices are packaged in 3–pin TO–92 (TO–226AA), micro size TSOP–5, 8–pin SOIC–8 and Micro8<sup>TM</sup> surface mount packages. The NCV device is packaged in SOIC–8.

Applications include direct monitoring of the 3.0 V or 5.0 V MPU/logic power supply used in appliance, automotive, consumer, and industrial equipment.

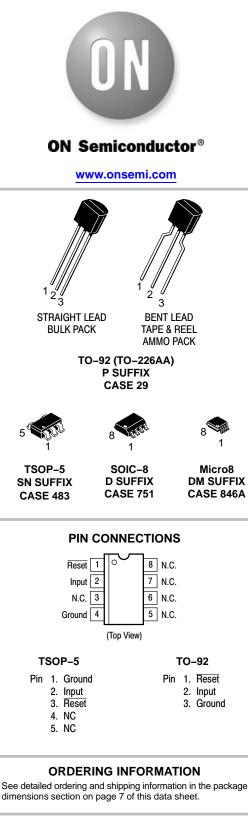
### Features

- Temperature Compensated Reference
- Monitors 3.0 V (MC34164–3) or 5.0 V (MC34164–5) Power Supplies
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 6.0 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation With 1.0 V Input
- Extremely Low Standby Current: As Low as 9.0 µA
- Economical TO–92 (TO–226AA), TSOP–5, SOIC–8 and Micro8 Surface Mount Packages
- NCV Prefix for Automotive and Other Applications Requiring Site and Control Changes
- These Devices are Pb-Free and are RoHS Compliant

## Input 🔿







### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 8 of this data sheet.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V <sub>in</sub>	-1.0 to 12	V
Reset Output Voltage	Vo	-1.0 to 12	V
Reset Output Sink Current	I <sub>Sink</sub>	Internally Limited	mA
Clamp Diode Forward Current, Reset to Input Pin (Note 1)	IF	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air D Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air DM Suffix, Plastic Package Maximum Power Dissipation @ $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Air	Ρ <sub>D</sub> R <sub>θJA</sub> Ρ <sub>D</sub> R <sub>θJA</sub> Ρ <sub>D</sub> R <sub>θJA</sub>	700 178 700 178 520 240	mW °C/W ™W °C/W mW °C/W
Operating Junction Temperature	ТJ	+150	°C
Operating Ambient Temperature Range MC34164 Series MC33164 Series, NCV33164	T <sub>A</sub>	0 to +70 - 40 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	– 65 to +150	°C
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM)	ESD	4000 200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### MC34164-3, MC33164-3 SERIES, NCV33164-3

**ELECTRICAL CHARACTERISTICS** (For typical values  $T_A = 25^{\circ}C$ , for min/max values  $T_A$  is the operating ambient temperature range that applies [Notes 2 & 3], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
COMPARATOR					
Threshold Voltage High State Output (V <sub>in</sub> Increasing) Low State Output (V <sub>in</sub> Decreasing) Hysteresis (I <sub>Sink</sub> = 100 μA)	V <sub>IH</sub> V <sub>IL</sub> V <sub>H</sub>	2.55 2.55 0.03	2.71 2.65 0.06	2.80 2.80 -	V
RESET OUTPUT					
Output Sink Saturation ( $V_{in} = 2.4 \text{ V}, I_{Sink} = 1.0 \text{ mA}$ ) ( $V_{in} = 1.0 \text{ V}, I_{Sink} = 0.25 \text{ mA}$ )	V <sub>OL</sub>		0.14 0.1	0.4 0.3	V
Output Sink Current (V <sub>in</sub> , Reset = 2.4 V)	I <sub>Sink</sub>	6.0	12	30	mA
Output Off–State Leakage (V <sub>in</sub> , Reset = 3.0 V) (V <sub>in</sub> , Reset = 10 V)	<sup>I</sup> R(leak)		0.02 0.02	0.5 1.0	μΑ
Clamp Diode Forward Voltage, Reset to Input Pin ( $I_F = 5.0 \text{ mA}$ )	V <sub>F</sub>	0.6	0.9	1.2	V

TOTAL DEVICE

Operating Input Voltage Range	V <sub>in</sub>	1.0 to 10	-	-	V
Quiescent Input Current $V_{in} = 3.0 V$ $V_{in} = 6.0 V$	l <sub>in</sub>	-	9.0 24	15 40	μΑ

1. Maximum package power dissipation limits must be observed. 2. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible. 3.  $T_{low} = 0^{\circ}$ C for MC34164  $T_{high} = +70^{\circ}$ C for MC34164

= -40°C for MC33164, NCV33164 = +125°C for MC33164, NCV33164

#### MC34164-5, MC33164-5 SERIES, NCV33164-5

**ELECTRICAL CHARACTERISTICS** (For typical values  $T_A = 25^{\circ}C$ , for min/max values  $T_A$  is the operating ambient temperature range that applies [Notes 5 & 6], unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
COMPARATOR					-
Threshold Voltage High State Output (V <sub>in</sub> Increasing) Low State Output (V <sub>in</sub> Decreasing) Hysteresis (I <sub>Sink</sub> = 100 μA)	V <sub>IH</sub> V <sub>IL</sub> V <sub>H</sub>	4.15 4.15 0.02	4.33 4.27 0.09	4.45 4.45 -	V
RESET OUTPUT					-
Output Sink Saturation $(V_{in} = 4.0 \text{ V}, \text{ I}_{Sink} = 1.0 \text{ mA})$ $(V_{in} = 1.0 \text{ V}, \text{ I}_{Sink} = 0.25 \text{ mA})$	V <sub>OL</sub>		0.14 0.1	0.4 0.3	V
Output Sink Current (V <sub>in</sub> , Reset = 4.0 V)	I <sub>Sink</sub>	7.0	20	50	mA
Output Off-State Leakage $(V_{in}, \overline{\text{Reset}} = 5.0 \text{ V})$ $(V_{in}, \overline{\text{Reset}} = 10 \text{ V})$	<sup>I</sup> R(leak)		0.02 0.02	0.5 2.0	μΑ
Clamp Diode Forward Voltage, Reset to Input Pin ( $I_F = 5.0 \text{ mA}$ )	V <sub>F</sub>	0.6	0.9	1.2	V
TOTAL DEVICE	•	•		•	•
Operating Input Voltage Range	V <sub>in</sub>	1.0 to 10	_	-	V
Quiescent Input Current	l <sub>in</sub>				μΑ

4. Maximum package power dissipation limits must be observed.

V<sub>in</sub> = 5.0 V

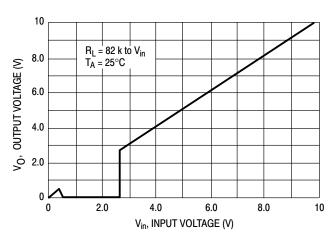
V<sub>in</sub> = 10 V

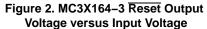
5. Low duty cycle pulse techniques are used during test to maintain junction temperature as close to ambient as possible.

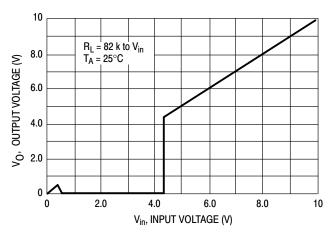
 $\overline{T}_{high}$  = +70°C for MC34164 6.  $T_{low} = 0^{\circ}C$  for MC34164

= -40°C for MC33164, NCV33164 = +125°C for MC33164, NCV33164

7. NCV prefix is for automotive and other applications requiring site and change control.







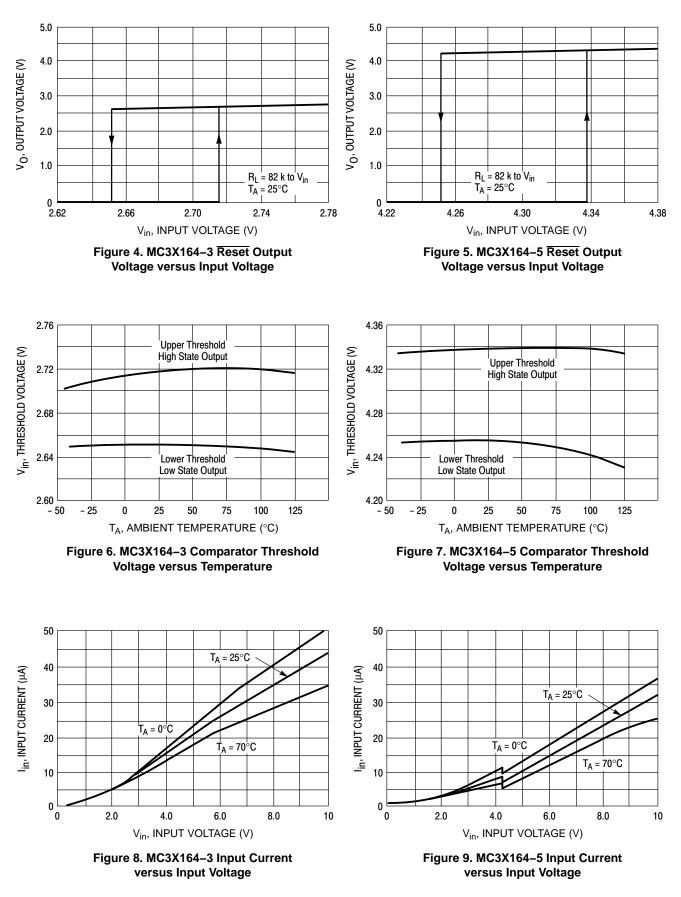
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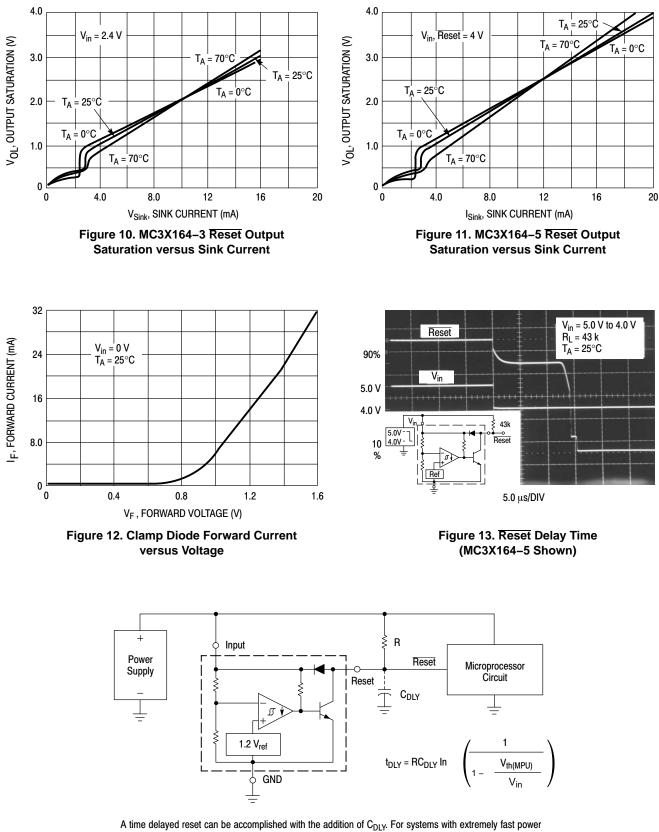
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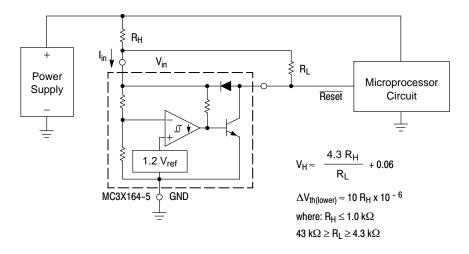
Figure 3. MC3X164-5 Reset Output Voltage versus Input Voltage





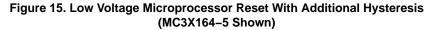
A time delayed reset can be accomplished with the addition of  $C_{DLY}$ . For systems with extremely fast power supply rise times (< 500 ns) it is recommended that the  $RC_{DLY}$  time constant be greater than 5.0  $\mu$ s.  $V_{th(MPU)}$  is the microprocessor reset input threshold.

Figure 14. Low Voltage Microprocessor Reset



	Test Data					
V <sub>H</sub> (mV)	∆V <sub>th</sub> (mV)	R <sub>Η</sub> (Ω)	R <sub>L</sub> (kΩ)			
60	0	0	43			
103	1.0	100	10			
123	1.0	100	6.8			
160	1.0	100	4.3			
155	2.2	220	10			
199	2.2	220	6.8			
280	2.2	220	4.3			
262	4.7	470	10			
306	4.7	470	8.2			
357	4.7	470	6.8			
421	4.7	470	5.6			
530	4.7	470	4.3			

Comparator hysteresis can be increased with the addition of resistor R<sub>H</sub>. The hysteresis equation has been simplified and does not account for the change of input current  $I_{in}$  as  $V_{in}$  crosses the comparator threshold (Figure 8). An increase of the lower threshold  $\Delta V_{th(lower)}$  will be observed due to  $I_{in}$  which is typically 10  $\mu$ A at 4.3 V. The equations are accurate to  $\pm$ 10% with R<sub>H</sub> less than 1.0 k $\Omega$  and R<sub>L</sub> between 4.3 k $\Omega$  and 43 k $\Omega$ .



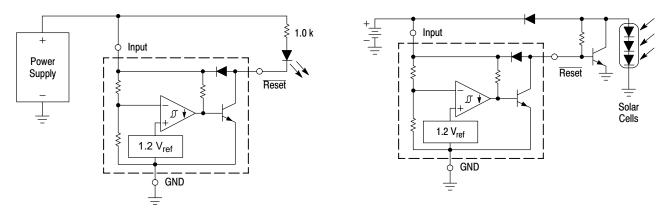


Figure 16. Voltage Monitor



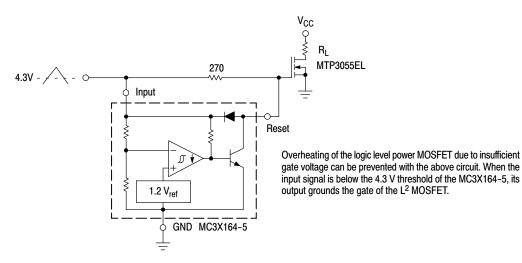


Figure 18. MOSFET Low Voltage Gate Drive Protection Using the MC3X164-5

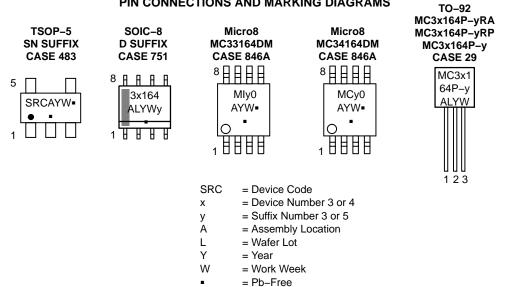
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC33164D-3G	SOIC-8 (Pb-Free)	98 Units / Rail
MC33164D-3R2G	SOIC-8 (Pb-Free)	2500 Heite / Tene & Deal
NCV33164D-3R2G*	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC33164DM-3R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC33164P-3G	TO–92 (Pb–Free)	2000 Units / Box
MC33164P-3RAG	TO–92 (Pb–Free)	2000 Units / Tape & Reel
MC33164P-3RPG	TO–92 (Pb–Free)	2000 Units / Pack
MC33164D-5G	SOIC-8 (Pb-Free)	98 Units / Rail
MC33164D-5R2G	SOIC-8 (Pb-Free)	
NCV33164D-5R2G*	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC33164DM-5R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC33164P-5G	TO–92 (Pb–Free)	2000 Units / Box
MC33164P-5RAG	TO–92 (Pb–Free)	2000 Units / Tape & Reel
MC33164P-5RPG	TO-92 (Pb-Free)	2000 Units / Pack
MC34164D-3G	SOIC-8 (Pb-Free)	98 Units / Rail
MC34164D-3R2G	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC34164DM-3R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC34164P-3G	TO–92 (Pb–Free)	2000 Units / Box
MC34164P-3RPG	TO–92 (Pb–Free)	2000 Units / Pack
MC34164D-5G	SOIC-8 (Pb-Free)	98 Units / Rail
MC34164D-5R2G	SOIC-8 (Pb-Free)	2500 Units / Tape & Reel
MC34164DM-5R2G	Micro8 (Pb–Free)	4000 Units / Tape & Reel
MC34164SN-5T1G	TSOP-5 (Pb-Free)	3000 Units / Tape & Reel
MC34164P-5G	TO-92 (Pb-Free)	2000 Units / Box
MC34164P-5RAG	TO-92 (Pb-Free)	2000 Units / Tape & Reel
MC34164P-5RPG	TO-92 (Pb-Free)	2000 Units / Pack

\*NCV33164:  $T_{low} = -40^{\circ}C$ ,  $T_{high} = +125^{\circ}C$ . Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

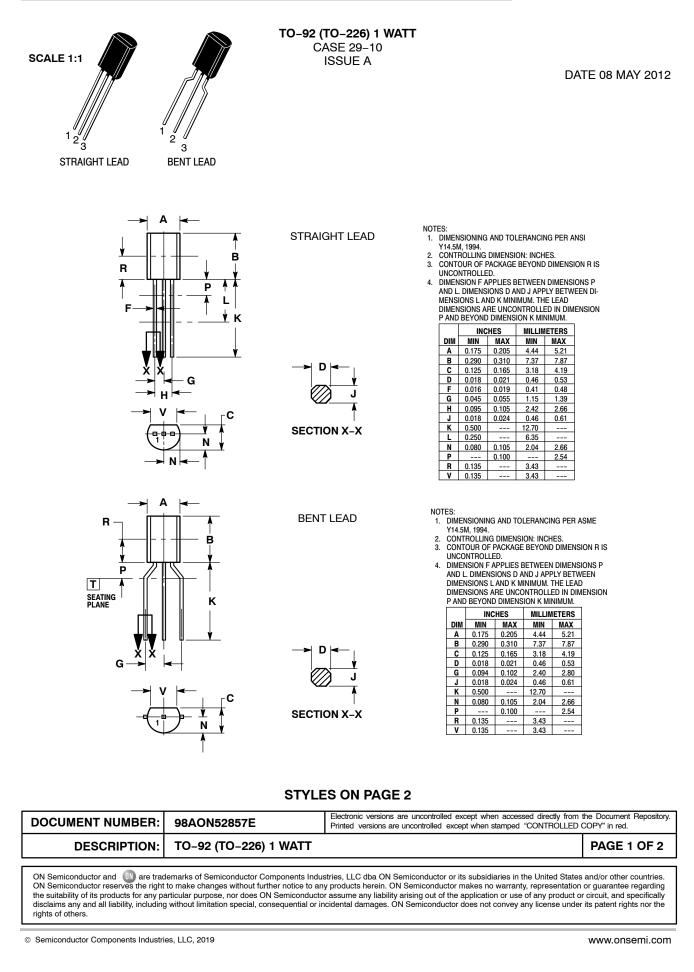
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### PIN CONNECTIONS AND MARKING DIAGRAMS



### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





#### **TO-92 (TO-226) 1 WATT** CASE 29-10 ISSUE A

## DATE 08 MAY 2012

	EMITTER BASE COLLECTOR								
	GATE SOURCE & SUBSTRATE DRAIN								
STYLE 11: PIN 1. 2. 3.	ANODE CATHODE & ANODE CATHODE	STYLE 12: PIN 1. 2. 3.	MAIN TERMINAL 1 Gate Main Terminal 2	STYLE 13: PIN 1. 2. 3.	ANODE 1 GATE CATHODE 2	STYLE 14: PIN 1. 2. 3.	EMITTER COLLECTOR BASE	STYLE 15: PIN 1. 2. 3.	ANODE 1 CATHODE ANODE 2
STYLE 16: PIN 1. 2. 3.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE CATHODE NOT CONNECTED	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	STYLE 20: PIN 1. 2. 3.	NOT CONNECTED CATHODE ANODE
STYLE 21: PIN 1. 2. 3.	COLLECTOR EMITTER BASE	STYLE 22: PIN 1. 2. 3.	SOURCE GATE DRAIN	STYLE 23: PIN 1. 2. 3.	GATE SOURCE DRAIN	STYLE 24: PIN 1. 2. 3.	EMITTER Collector/Anode Cathode	STYLE 25: PIN 1. 2. 3.	MT 1 GATE MT 2
STYLE 26: PIN 1. 2. 3.	V <sub>CC</sub> GROUND 2 OUTPUT	STYLE 27: PIN 1. 2. 3.	MT SUBSTRATE MT	STYLE 28: PIN 1. 2. 3.	CATHODE ANODE GATE	STYLE 29: PIN 1. 2. 3.	NOT CONNECTED ANODE CATHODE	STYLE 30: PIN 1. 2. 3.	DRAIN GATE SOURCE
STYLE 31: PIN 1. 2. 3.	GATE DRAIN SOURCE	STYLE 32: PIN 1. 2. 3.	BASE COLLECTOR EMITTER	STYLE 33: PIN 1. 2. 3.	RETURN INPUT OUTPUT	STYLE 34: PIN 1. 2. 3.	INPUT Ground Logic	STYLE 35: PIN 1. 2. 3.	GATE COLLECTOR EMITTER

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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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#### SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR З. 4. EMITTER EMITTER 5. BASE 6. 7 BASE 8. EMITTER STYLE 5: PIN 1. DRAIN 2. DRAIN З. DRAIN DRAIN 4. 5. GATE 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6. BASE, DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3. SOURCE GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. 4. TXE 5. RXE 6. VFF GND 7. 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 З. CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C З. REXT 4. GND 5. IOUT 6. IOUT 7. IOUT 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. EMITTER, #1 BASE, #2 2. З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 З. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: PIN 1. GROUND BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND BIAS 2 INPUT 6. 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. 5. P-DRAIN 6. P-DRAIN N-DRAIN 7. 8. N-DRAIN STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC I/O LINE 3 4. 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt ENABLE З. 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: PIN 1. DRAIN 1 DRAIN 1 2 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1
STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd
STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1
STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON
STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1
STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT
STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN

#### DATE 16 FEB 2011

STYLE 4: ANODE ANODE PIN 1. 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE, #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE SOURCE 2. 3. 4. GATE 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE 2. EMITTER З. COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE CATHODE COLLECTOR/ANODE 6. 7. COLLECTOR/ANODE 8. STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET 3. 4. GND 5. 6. V MON VBULK 7. VBULK 8. VIN

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SOURCE 1/DRAIN 2

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8. GATE 1

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